

# Continental Device India Limited

An ISO/TS16949 and ISO 9001 Certified Company



### **SOT-23 Formed SMD Package**

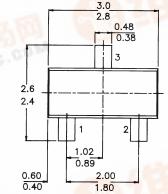
### **CMBT3906**

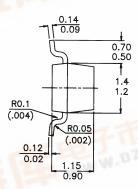
# SILICON EPITAXIAL TRANSISTOR

P-N-P transistor

Marking CMBT3906 = 2A

PACKAGE OUTLINE DETAILS
ALL DIMENSIONS IN mm





#### Pin configuration

1 = BASE

2 = EMITTER

3 = COLLECTOR



#### ABSOLUTE MAXIMUM RATINGS

Collector-base voltage (open emitter)
Collector-emitter voltage (open base)
Emitter-base voltage (open collector)
Collector current (d.c.)
Total power dissipation up to  $T_{amb} = 25$  °C
D.C. current gain

$$-I_C = 10$$
 mA;  $-V_{CE} = 1$  V  
Transition frequency at  $f = 100$  MHz  
 $-I_C = 10$  mA;  $-V_{CE} = 20$  V

$$f_T$$
 min. 250 MHz



# **CMBT3906**

RATINGS			
Limiting values			
Collector-base voltage (open emitter)	$-V_{CB0}$	max.	40 V
Collector-emitter voltage (open base)	$-V_{CE0}$	max.	40 V
Emitter-base voltage (open collector)	$-V_{EB0}$	max.	5 V
Collector current (d.c.)	$-I_C$	max.	200 mA
Total power dissipation			
$up to T_{amb} = 25  ^{\circ}C$	$P_{tot}$	max.	250  mW
Storage temperature	$T_{stg}$	-55 to	+150 °C
THERMAL CHARACTERISTICS			
$T_{j} = P(R_{th j-t} + R_{th t-s} + R_{th s-a}) + T_{amb}$			
Thermal resistance			
from junction to ambient	$R_{th\ j-a}$	=	<i>500</i> K/W
CHARACTERISTICS			
$T_{amb} = 25$ °C unless otherwise specified			
Collector-emitter breakdown voltage			
$-I_C = 1 \text{ mA}; I_B = 0$	$-V_{(BR)CE0}$	min.	40 V
Collector-base breakdown voltage			
$-I_C = 10\mu A; I_E = 0$	$-V_{(BR)CB0}$	min.	40 V
Emitter-base breakdown voltage			
$-I_E = 10 \ \mu A; I_C = 0$	$-V_{(BR)EB0}$	min.	5 V
Collector cut-off current			
$-V_{CE} = 30 \ V; \ -V_{EB} = 3 \ V$	$-I_{CEX}$	max.	50 nA
Base current			
with reverse biased emitter junction	$-I_{BEX}$	max,	50 nA
Output capacitance at $f = 100 \text{ kHz}$			
$I_E = 0$ ; $-V_{CB} = 5 V$	$C_{c}$	max,	4,5 pF
Input capacitance at $f = 100 \text{ kHz}$			
$I_C = 0; -V_{BE} = 0.5 V$	$C_e$	max.	10 pF
Saturation voltages			
$-I_C = 10 \text{ mA; } -I_B = 1 \text{ mA}$	-V <sub>CEsat</sub>	max.	0,25 V
$-I_C = 50 \text{ mA}; -l_B = 5 \text{ mA}$	-V <sub>CEsat</sub>	max.	0,4 V
$-I_C = 10 \text{ mA; } -I_B = 1 \text{ mA}$	-V <sub>BEsat</sub>	max.	0,85 V
		min.	0,65 V
$-I_C = 50 \text{ mA}; -I_B = 5 \text{ mA}$	-V <sub>BEsat</sub>	max.	0,95 V
D.C. current gain			
$-I_C = 0.1 \text{ mA; } -V_{CE} = 1 \text{ V}$	$h_{FE}$	min.	60
$-I_C = 1 \text{ mA; } -V_{CE} = 1 \text{ V}$	$h_{FE}$	min.	80
$-I_C = 10 \text{ mA; } -V_{CE} = 1 \text{ V}$	$h_{FE}$	min.	100
10 10 mm, v CE - 1 v	**FE	max.	300
		man.	500

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$-I_C = 50 \text{ mA; } -V_{CE} = 1 \text{ V}$	$h_{\!F\!E}$	min.	60
$-I_C = 100 \text{ mA; } -V_{CE} = 1 \text{ V}$	$h_{FE}$	min.	30
Transition frequency at $f = 100 \text{ MHz}$			
$-I_C = 10mA; -V_{CE} = 20V$	$f_T$	min.	250 MHz
Noise figure at $R_S = 1 k\Omega$			
$-I_C = 100 \mu A; -V_{CE} = 5 V$			
f = 10  Hz to  15.7  kHz	F	max.	4 dB
Small Signal Current Gain			
$V_{CE} = 10V$ ; $I_C = 1$ mA; $f = 1$ KHz	$h_{fe}$	min.	100
		max.	400

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